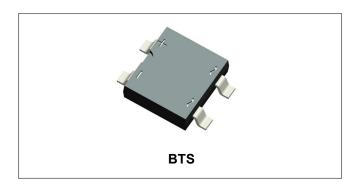


SM05S THRU SM10S

Technical Data Data Sheet N1008, Rev. B



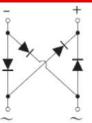
SM05S THRU SM10S SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIERS



Features

- Rating to 1000V PRV
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique
- results in inexpensive product
- Lead tin plated copper
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Polarity : Symbol molded on body
- Mounting position: Any

Maximum Ratings @T_A=25°C unless otherwise specified

Type Number	Symbol	SM05S	SM1S	SM2S	SM4S	SM6S	SM8S	SM10S	Units
Peak Repetitive Reverse Voltage DC Blocking Voltage	V _{RRM} V _{DC}	50	100	200	400	600	800	1000	V
RMS Voltage	VRMS	35	70	140	280	420	480	700	V
Average Rectified Output Current @T _A =40 $^{\circ}$ C	lo	0.8						А	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30						А	



Technical Data Data Sheet N1008, Rev. B

SM05S THRU SM10S

RoHS 🧭

Electrical Characteristics:@T _A =25°C unless otherwise specified									
Type Number	Symbol	SM05S	SM1S	SM2S	SM4S	SM6S	SM8S	SM10S	Units
Forward Voltage per element @I _F =0.8A	Vfm				1.1				V
Peak Reverse Current@T _A = 25°CAt Rated DC Blocking Voltage@T _A = 125°C	I _R	5 500				μA			
Typical Junction Capacitance (Note 1)	Cj				13				pF

* Pulse width < 300 $\mu s, \ duty \ cycle < 2\%$

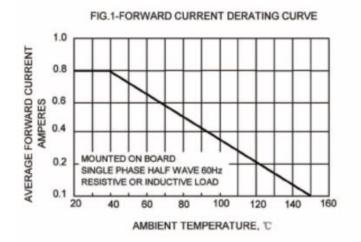
Thermal-Mechanical Specifications:@T_A=25°C unless otherwise specified

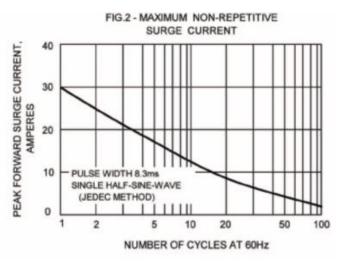
Type Number	Symbol	SM05S	SM1S	SM2S	SM4S	SM6S	SM8S	SM10S	Units
Typical Thermal Resistance per leg (Note 2)	R _{θJC}	75					°C/W		
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55+150					°C		

Note: 1. Measured at 1.0 MHZ and applied reverse voltage of 4.0 VDC

2. Thermal resistance junction to case

Ratings and Characteristics Curves



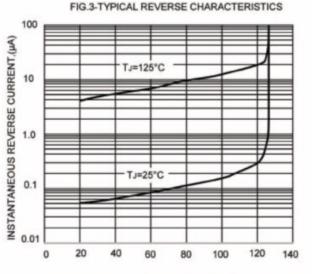




Technical Data Data Sheet N1008, Rev. B



RoHS 🗭



PERCENT OF RATED PEAK REVERSE VOLTAGE. (%)

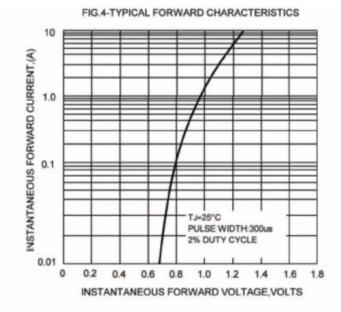
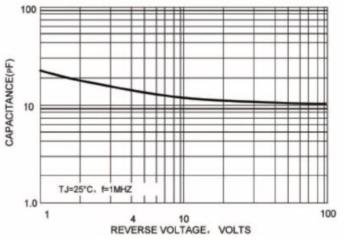


FIG.5-TYPICAL JUNCTION CAPACITANCE

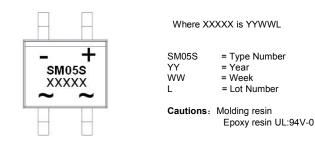


Ordering Information

Device	Package	Shipping
SM05S THRU SM10S	BTS (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



China - Germany - Korea - Singapore - United States

http://www.smc-diodes.com - sales@ smc-diodes.com

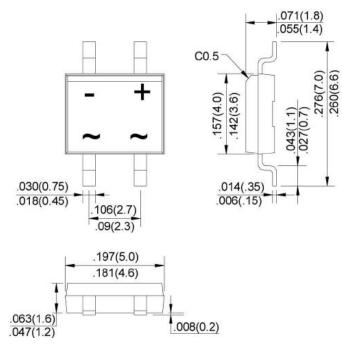


SM05S THRU SM10S

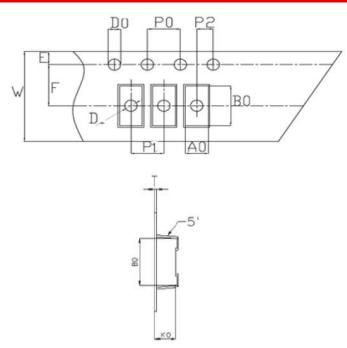
Technical Data Data Sheet N1008, Rev. B

RoHS 🗭

Mechanical Dimensions BTS(Inches/Millimeters)



Carrier Tape Specification BTS



SYMBOL	Millimeters						
STMBOL	Min.	Max.					
A0	4.92	5.12					
B0	7.12	7.32					
D0	1.50	1.60					
D1	1.40	1.60					
P0	3.90	4.10					
P1	7.90	8.10					
P2	1.95	2.05					
E	1.65	1.85					
K0	2.78	2.98					
F	5.45	5.55					
W	11.90	12.10					
Т	0.24	0.30					
10P0	39.80	40.20					
抗拉拉力	≥3KG						

- China Germany Korea Singapore United States
 Atta://www.smc.diodes.com sales@ smc.diodes.com -
 - http://www.smc-diodes.com sales@ smc-diodes.com



Technical Data Data Sheet N1008, Rev. B





DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..